

UM4701/4711/8701/8711

Multi-line ESD/EMI Protection for Color LCD Interfaces UM4701 DFN8 2.0×2.0 UM4711 DFN8 1.7×1.3 UM8701 DFN16 4.0×1.6 UM8711 DFN16 3.3×1.3

General Description

The UM4701/UM4711/UM8701/UM8711 is a (L-C) low pass filter array with integrated TVS diodes. It is designed to suppress unwanted EMI signals and provide electrostatic discharge (ESD) protection in portable electronic equipment. This device utilizes solid-state silicon-avalanche technology for superior clamping performance and DC electrical characteristics. They have been optimized for protection of color LCD and camera lines in cellular phones and other portable electronics.

The device consists of identical circuits comprised of TVS diodes for ESD protection, and a 5 pole inductor-capacitor network for EMI filtering. A typical inductor value of 19nH and a capacitor value of 12pF are used to achieve 30dB minimum attenuation from 800MHz to 2.7GHz. The TVS diodes provide effective suppression of ESD voltages in excess of \pm 15kV (air discharge) and \pm 8kV (contact discharge) per IEC 61000-4-2, level 4.

The UM4701 is in a RoHS compliant DFN8 2.0×2.0 package, the UM4711 is in a RoHS compliant DFN8 1.7×1.3 package, the UM8701 is in a RoHS compliant DFN16 4.0×1.6 package and the UM8711 is in a RoHS compliant DFN16 3.3×1.3 package. The leads are finished with lead-free. The small package makes it ideal for use in portable electronics such as cell phones, digital still cameras, and PDAs.

Applications

- Color LCD Protection
- Cell Phone CCD Camera Lines
- Clamshell Cell Phones

Features

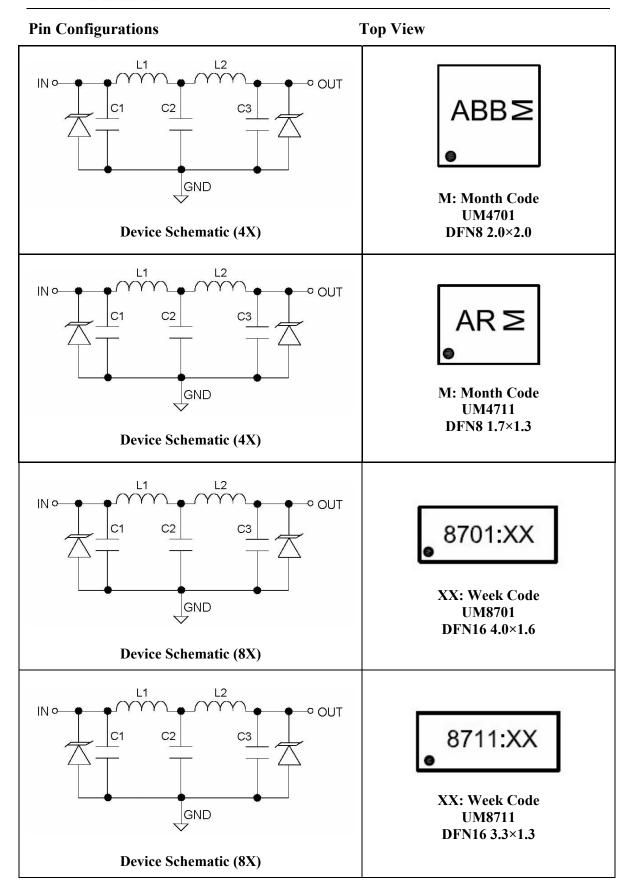
- Bidirectional EMI Filter with Integrated TVS for ESD Protection
- ESD Protection to IEC 61000-4-2 (ESD) Level 4, ±15kV (air), ±8kV (contact)
- Filter performance: 30dB minimum attenuation from 800MHz to 2.7GHz
- TVS Working Voltage: 5V
- Inductor: 19nH (Typical)
- Capacitors: 12pF (Typical at $V_R = 2.5V$)
- Protection and filtering for multi lines UM4701/4711: four lines
- UM8701/8711: eight linesSolid-state Technology

Part Number	Working Voltage	Packaging Type	Channel	Marking Code	Shipping Qty
UM4701	5.0V	DFN8 2.0×2.0	4	ABB	
UM4711	5.0V	DFN8 1.7×1.3	4	AR	3000pcs /7Inch
UM8701	5.0V	DFN16 4.0×1.6	8	8701	Tape & Reel
UM8711	5.0V	DFN16 3.3×1.3	8	8711	

Ordering Information



UM4701/4711/8701/8711





Absolute Maximum Ratings

PARAMETER	SYMBOL	VALUE	UNIT
ESD per IEC 61000-4-2(Air) ESD per IEC 61000-4-2(Contact)	V_{ESD}	+/- 20 +/- 15	kV
Junction Temperature	T _J	125	°C
Operating Temperature Range	T _{OP}	-40 to 85	°C
Storage Temperature Range	T _{STG}	-55 to 150	°C

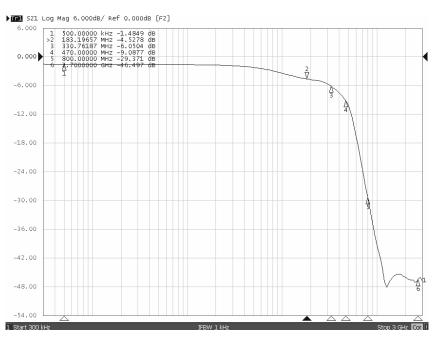
Electrical Characteristics

($T_J=25$ °C unless otherwise noted)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
TVS Reverse Stand-Off Voltage	V _{RWM}				5	V
TVS Reverse Breakdown Voltage	V_{BR}	It = 1mA	6	8	10	V
TVS Reverse Leakage Current	I _R	$V_{RWM} = 3.3V$			0.1	μΑ
DC Resistance	R _{cc}			18		Ω
Roll-off frequency at -6dB Attenuation	f_R	Z source = Z_{load} = 50 Ω		300		MHZ
Filter Cut-Off Frequency	fc	Z source = Z_{load} = 50 Ω		150		MHZ
Inductance	L			19		nH
Total series Inductance	L_1+L_2	Each Line		38		nH
Capacitance	Cd	$V_R = 2.5V, f = 1MHZ$		12	15	pF
Total Capacitance	C _{total}	Input to Gnd, Each Line V _R =2.5V,f=1MHZ		36	45	pF

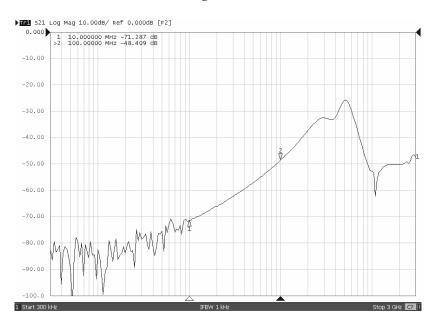


Typical Operating Characteristics



Typical Insertion Loss

Analog Crosstalk





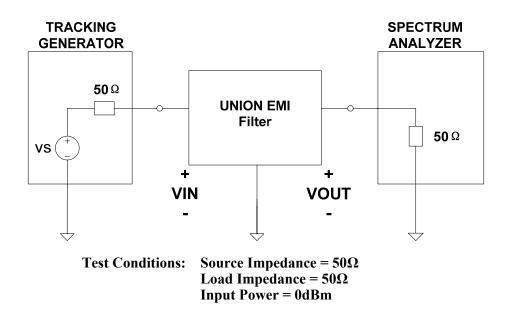
Applications Information

Insertion Loss

Insertion Loss (IL) is used to describe the transmission coefficient between two points in a circuit often described in terms of dB. When examining S parameters, S21 is often described as insertion loss. Insertion Loss and S21 will be used interchangeably from here on out. The insertion loss of a circuit with VOUT and VIN would be expressed as

 $IL = S_{21}(dB) = 20 \log (V_{OUT}/V_{IN})$

The setup for measuring insertion loss in a 50 Ω system is shown in the figure below. It will be analyzed in a 50 Ω environment, so the source impedance and load impedance is 50 Ω . The transfer functions then can be analyzed in terms of insertion loss (S21).



Cut Off Frequency

Cut off Frequency is the frequency at which the signal strength is 3.0 dB less than it is Pass Band 3.0 dB of attenuation equates to half the original signal power. The Pass Band is the range of frequencies that are allowed to "pass" through a filter with minimal attenuation. For our purposes it starts from DC and ends at the cut off frequency.

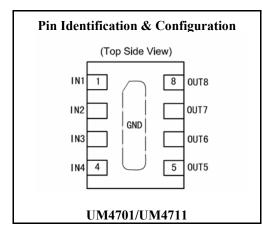
Device Connection

The UM4701/UM4711/UM8701/UM8711 is comprised of identical circuits consisting of a low pass filter for EMI suppression and dual TVS diodes for ESD protection. The device is in an 8-pin DFN and 16-pin DFN package. Electrical connection is made to all the pins located at the bottom of the device. A center tab serves as the ground connection. The device has a flow through design for easy layout. All path lengths should be kept as short as possible to minimize the effects of parasitic inductance in the board traces.

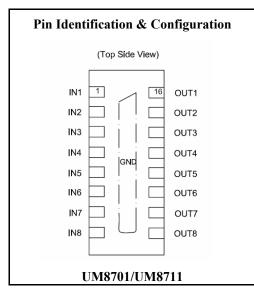


Ground Connection Recommendation

Parasitic inductance (L) present in the board layout will affect the filtering performance of the device. As frequency (f) increases, the effect of the inductance becomes more dominant. This effect is given by Equation 1.



Pin	Identification
1 - 4	Input Lines
5 - 8	Output Lines
Center Tab	Ground
Equation 1: The Imped: Frequency XLF	ance of an inductor at
$XLF(L,f) = 2 \times_{\pi} \times f \times L$ Where: L= Inductance (H) f = Frequency (Hz)	



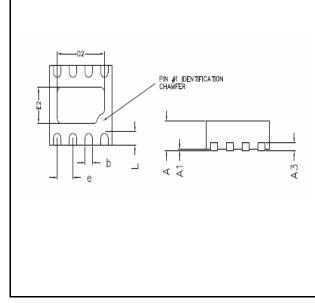
Pin	Identification
1 - 8	Input Lines
9 - 16	Output Lines
Center Tab	Ground
Where: L= parasitic inductance	n the PCB (H)
XLF(L, f) = $2 \times_{\Pi} \times f \times L$ Where: L= parasitic inductance if f = Frequency (Hz)	n the PCB (H)
Where: L= parasitic inductance i	n the PCB (H)



Package Information

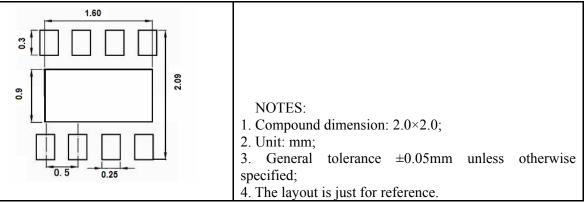
UM4701: DFN8 2.0×2.0

Outline Drawing



	DIMEN	ISIONS		
Symbol	MILLIMETERS			
Symbol	Min	Тур	Max	
D	1.95	2.00	2.05	
Е	1.95	2.00	2.05	
D2	1.35	1.50	1.65	
А	0.57	0.69	0.80	
A1	0	0.02	0.05	
A3	-	0.152	0.20	
b	0.18	0.25	0.30	
E2	0.75	0.90	1.00	
L	0.20	0.30	0.40	
e	-	0.50	-	

Land Pattern

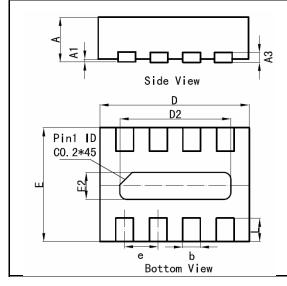






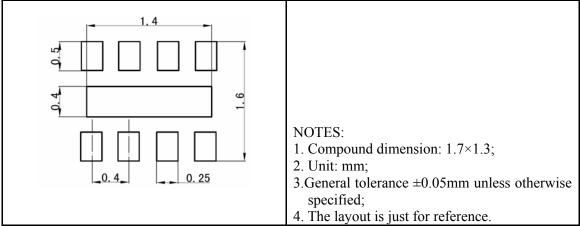
UM4711: DFN8 1.7×1.3

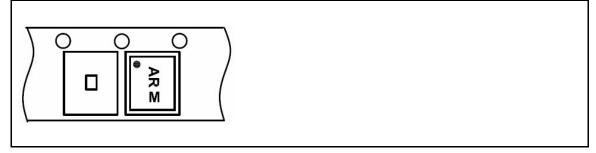
Outline Drawing



	DIMEN	SIONS		
Symbol	MILLIMETERS			
Symbol	Min	Тур	Max	
D	1.624	1.70	1.776	
Е	1.25	1.30	1.426	
D2	1.10	1.40	1.70	
E2	0.20	0.30	0.50	
А	0.47	0.55	0.60	
A1	0	0.02	0.05	
A3	-	0.15	-	
b	0.13	0.20	0.25	
L	0.15	0.25	0.35	
e	-	0.40	-	

Land Pattern

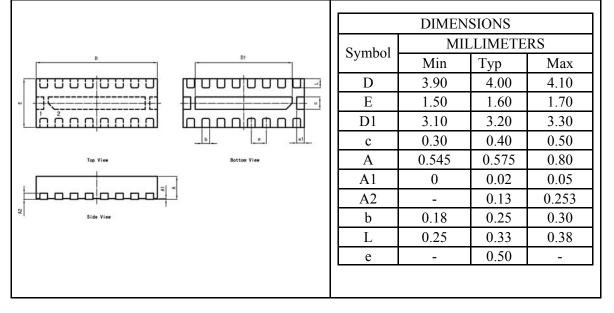




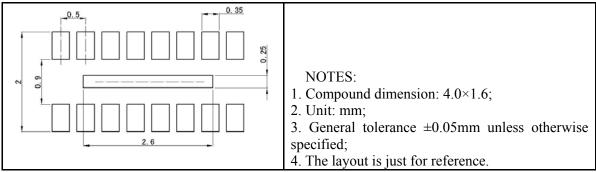


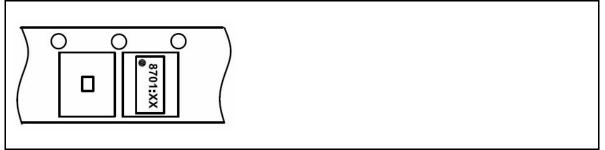
UM8701: DFN16 4.0×1.6

Outline Drawing



Land Pattern

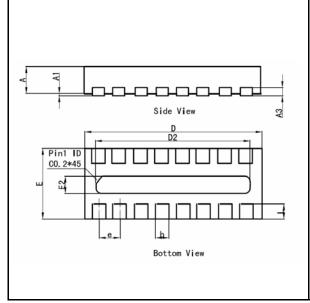






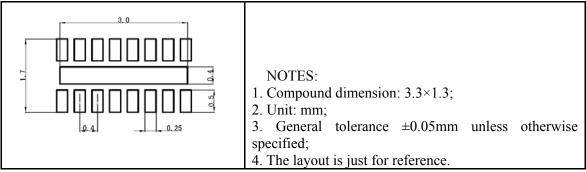
UM8711: DFN16 3.3×1.3

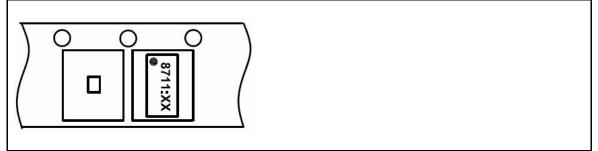




	DIMEN	ISIONS		
Symbol	MILLIMETERS			
Symbol	Min	Тур	Max	
D	3.224	3.30	3.376	
Е	1.25	1.30	1.426	
D2	2.45	2.90	3.00	
E2	0.20	0.30	0.50	
А	0.47	0.55	0.60	
A1	-	0.02	0.05	
A3	-	0.15	-	
b	0.13	0.20	0.25	
L	0.17	0.25	0.37	
e	-	0.40	-	

Land Pattern







IMPORTANT NOTICE

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